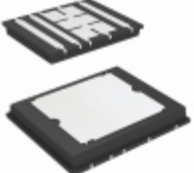
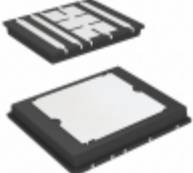
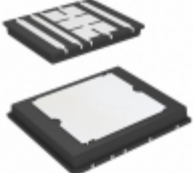
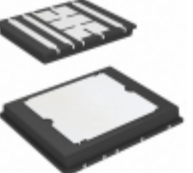
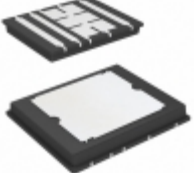



	<h2>SIE862DF-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIE862DF-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 50A POLARPAK</p> <p>Datenblätter:  SIE862DF-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIE862DF-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 50A POLARPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3000 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	10-PolarPAK® (U)
Supplier Device-Gehäuse	10-PolarPAK® (U)
Verlustleistung (max)	5.2W (Ta), 104W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	50A (Tc)
Rds On (Max) @ Id, Vgs	3.2 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	75nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3100pF @ 15V
Verpackung	Tape & Reel (TR)

SIE862DF-T1-GE3 ist neu im Original, Suche SIE862DF-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIE862DF-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIE862DF-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIE864DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 45A POLARPAK</p>	 <p>SIE860DF-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A POLARPAK</p>	 <p>SIE864DF-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 45A POLARPAK</p>	 <p>SIE862DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 50A POLARPAK</p>
 <p>SIE860DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A POLARPAK</p>	 <p>SIE862DF vishay SIE862DF vishay</p>	 <p>SIE860DF-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 60A POLARPAK</p>	 <p>SIE864DP-T1-GE3 VISHAY SIE864DP-T1-GE3 VISHAY</p>

heiße Teile

Mehr

AM30N06-39D-T1-PF	AS1130-BWLT	AT45DB021D-SH-B	B30810-D2034-Y419-W03	CC1206JKNP0DBN680
CD74HCT158E	CDPH4D19FNP-6R8MC	CGA6M4X7T2W224K200AE	CRS-0515W200	DG4052EEQ-T1-GE3
ESDA6V2S6RL	ISL28230FUZ	L296H-12	LM3450MTX	LMC7101AIM
LTC3025IDC#TRPBF	M52758FP#CGOG	MB89935BPFV-GS-251-BND	MC68HC11F1CVFR2	MMZ1608A252BTA00
RFW-D100-LF	SD500OC30R	SD600OC12R	SE2537L-R	SIE01-03
SIE01-06	SIE20031	SIE20034	SIE501.8LT	SIE503.3LT
SIE503.3LTR	SIE800DF-T1-E3	SIE800DF-T1-E3	SIE802DF-T1-E3	SIE802DF-T1-E3
SIE808DF-T1-E3	SIE808DF-T1-E3	SIE812DF	SIE848DF-T1-E3	SIE848DF-T1-E3
SIE862DF-T1-GE3	SIE864DP-T1-GE3	SIE874DF-T1-GE3	SIE874DF-T1-GE3	SK50DA100DBL3
SKY77584-11	SN65220YZBR	ST16C450IJ44-F	TDA9851T	V5.5MLA0603LNR

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited